Reg. No.

Question Paper Code : 51645

B.E/B.Tech. DEGREE EXAMINATION, MAY/JUNE 2016

Second Semester

Civil Engineering

GE 2151 / 10133 EE 206/EE 1153/EE 26/080280011 – BASIC ELECTRICAL AND ELECTRONICS ENGINEERING

(Common to all Branches)

(Regulations 2008/2010)

Time : Three Hours

Maximum : 100 Marks

(nerged)

Answer ALL questions. PART – A $(10 \times 2 = 20 \text{ Marks})$

- 1. Two resistances of 4 Ω and 6 Ω are connected in parallel across 10 V battery. Determine the current through 6 Ω resistance.
- 2. Define RMS value.
- 3. Define voltage regulation of a transformer.
- 4. Why is starter necessary for a dc motor ?
- 5. Compare PN junction diode and Zener diode.
- 6. What is effect of saturation of a transistor ?
- 7. Define Flip-Flop.
- 8. What are the different sources of errors in DAC?

- 9. As related to amplitude modulation, what is overmodulation, undermodulation and 100% modulation?
- 10. Why are digital signals said to be noise immune?

$PART - B (5 \times 16 = 80 Marks)$

- 11. (a) (i) Explain the working of Single-Phase Energy Meter with necessary diagram. (8)
 - (ii) Calculate the
 - (1) Form Factor and
 - (2) Peak Factor of a full wave rectified sine wave.

OR

- (b) (i) Explain the operation of attraction type of M.I instrument. (8)
 - (ii) Explain the working of Dynamometer type wattmeter with necessary diagram. (8)
- 12. (a) Explain the construction and working principle of DC generator with neat diagram. (16)

OR

- (b) Explain the working principle of various types of Single Phase (1φ) Induction
 Motor with neat diagram. (16)
- 13. (a) (i) With neat diagrams, explain how a voltage regulator circuit regulates the output voltage under the following conditions :
 - (1) Load resistance increases
 (2) Input voltage decrease
 (4)
 - (ii) (1) Using the two diode analogy, explain why the base-emitter junction has to be forward biased to provide collector current.
 - (2) Sketch a common emitter amplifier circuit with an NPN transistor. (8)

OR

(8)

- (b) (i) (1) Explain the avalanche effect that accounts for the reverse breakdown voltage (PIV) of a diode. (4)
 (2) What is the effect on capacitance of a PN junction diode as forward and reverse bias are applied? (4)
 (ii) (1) Explain the amplifying action of a transistor. (6)
 (2) In a CE, I_B changes from 100 μA to 150 μA which causes a change in
 - I_{C} from 5 mA to 7.5 mA. If V_{CE} is held constant at 10 V, find β_{ac} (h_{fe}). (2)
- (a) Write short notes on :

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- (i) RS flip-flop
- (ii) D flip-flop
- (iii) JK flip-flop
- (iv) T flip-flop

OR

- (b) With necessary diagrams, explain the functioning of any one type of ADC and DAC. (16)
- (a) Why modulation is necessary? Write in detail about frequency modulation.

OR

(b) Discuss the usage of satellite for long distance communication with a neat block diagram of basic satellite transponder.

(16)